501.36931X00

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant(s):

IWASAKI, et al.

Serial No.:

09/255,856

Filed:

February 23, 1999

For:

SEMICONDUCTOR DEVICE WITH LAYERED INTERCONNECT

STRUCTURE (AS AMENDED)

Group:

2813

Examiner:

S. Smoot

<u>AMENDMENT</u>

Assistant Commissioner for Patents Washington, D.C. 20231

November 13, 2000

Sir:

In response to the Office Action mailed July 10, 2000, please amend the above-identified application as follows:

IN THE SPECIFICATION

Please delete the present title in its entirety, and substitute therefor the following:

--SEMICONDUCTOR DEVICE WITH LAYERED INTERCONNECT TC 2800 MALL 2000 MALL 200 STRUCTURE--.

IN THE CLAIMS

and add the following new claims to the application:

A semiconductor device having a layered interconnection strúcture including a copper film or a

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80.06 OP 144,700 OP

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